Absolute Maximum Ratings (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-50	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-100	mA
Peak Collector Current	I_{CM}	-200	mA
Peak Base Current	I_{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6) Total Device	P_D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 6)	$R_{\theta JA}$	625	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	°C

ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic (Note 8)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-50	—	—	V	I_C = 100µA, I_B = 0
Collector-Emitter Breakdown Voltage	BV_{CEO}	-45	—	—	V	I_C = 10mA, I_B = 0
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	I_E = 100µA, I_C = 0
DC Current Gain	h_{FE}	220	—	475	—	V_{CE} = -5.0V, I_C = -2.0mA
DC Current Gain matching (Note 9)	h_{FE1}/ h_{FE2}	0.9	1	—	—	V_{CE} = -5.0V, I_C = -2.0mA
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	-100 -400	mV	I_C = -10mA, I_B = -0.5mA I_C = -100mA, I_B = -5.0mA
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	—	-700	—	mV	I_C = -10mA, I_B = -0.5mA
Base-Emitter Voltage	$V_{BE(on)}$	-580	-665	-750	mV	V_{CE} = -5.0V, I_C = -2.0mA
Base-Emitter Voltage matching (Note 10)	$V_{BE1(on)}$ - $V_{BE2(on)}$	—	—	2	mV	V_{CE} = -5.0V, I_C = -2.0mA
Base-Emitter Voltage	$V_{BE(on)}$	-580	-665	-750	mV	V_{CE} = -5.0V, I_C = -2.0mA
Collector-Cutoff Current	I_{CBO}	— —	— —	-15 -4.0	nA µA	V_{CB} = -30V V_{CB} = -30V, T_A = +150°C
Emitter Cutoff Current	I_{EBO}	—	—	-100	nA	V_{EB} = -5.0V, I_C = 0
Gain Bandwidth Product	f_T	100	—	—	MHz	V_{CE} = -5.0V, I_C = -10mA, f = 100MHz
Collector-Base Capacitance	C_{CBO}	—	2	3	pF	V_{CB} = -10V, f = 1.0MHz
Emitter-Base Capacitance	C_{EBO}	—	11	—	pF	V_{EB} = -0.5V, f = 1.0MHz

Notes:
6. For a device mounted on minimum recommended pad layout with 1oz copper that is on a single-sided 1.6mm FR4 PCB; the device is measured under still air conditions whilst operating in a steady-state.
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.
8. Short duration pulse test used to minimize self-heating effect.
9. The smaller of the two values is taken as the numerator.
10. The smaller of the two values is subtracted from the larger value.

Typical Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

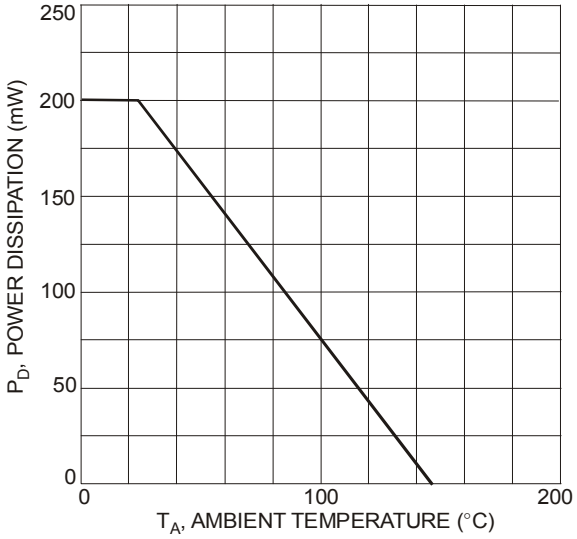


Fig. 1 Power Dissipation vs. Ambient Temperature

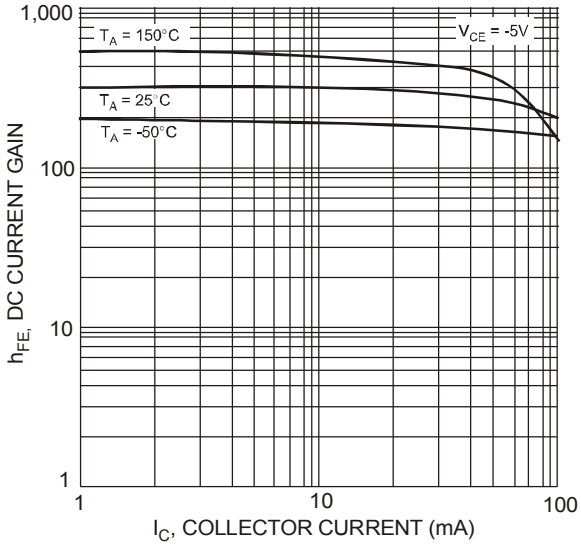


Fig. 2 Typical DC Current Gain vs. Collector Current

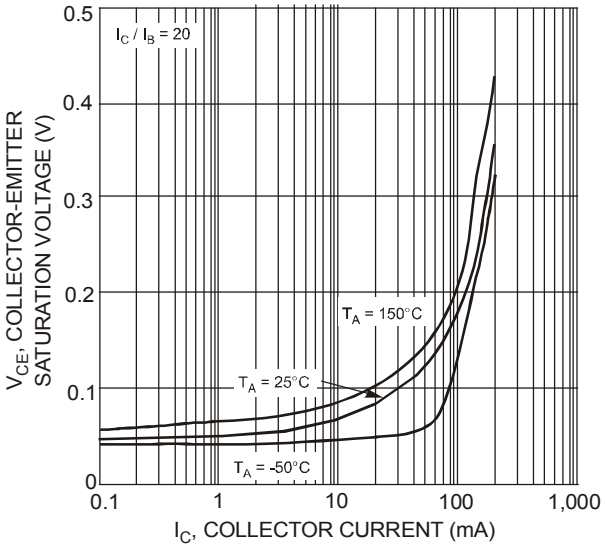


Fig. 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

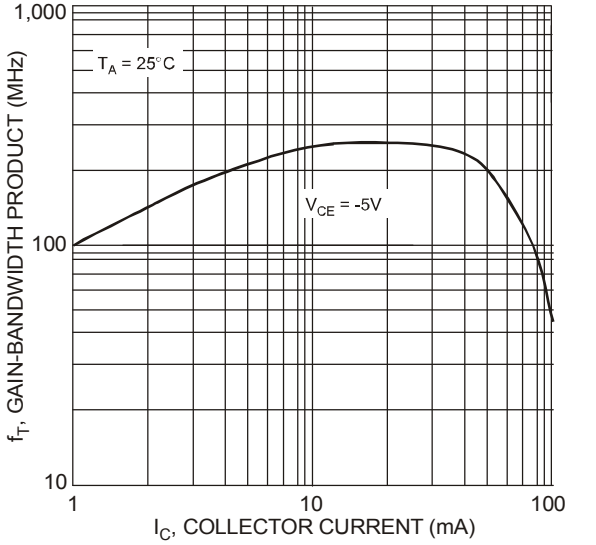
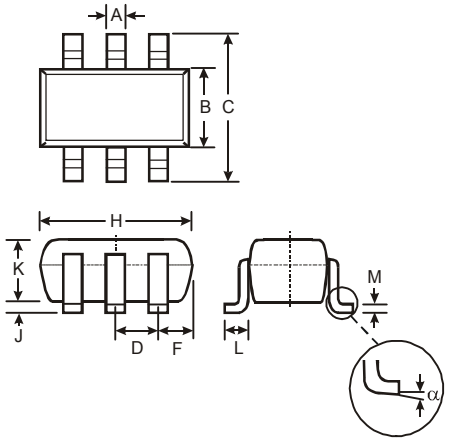


Fig. 4 Typical Gain-Bandwidth Product vs. Collector Current

Package Outline Dimensions

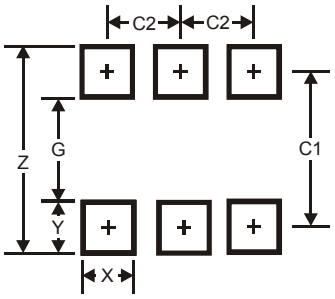
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT363			
Dim	**Min**	**Max**	**Typ**
A	0.10	0.30	0.25
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	0.65 Typ		
F	0.40	0.45	0.425
H	1.80	2.20	2.15
J	0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.22	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
X	0.42
Y	0.6
C1	1.9
C2	0.65

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